

## TPA6111A2 150-mW Stereo Audio Power Amplifier

### 1 Features

- 150-mW Stereo Output
- PC Power Supply Compatible
  - Fully Specified for 3.3-V and 5-V Operation
  - Operation to 2.5 V
- Pop Reduction Circuitry
- Internal Midrail Generation
- Thermal and Short-Circuit Protection
- Surface-Mount Packaging
  - PowerPAD™ MSOP
  - SOIC
- Pin Compatible With TPA122, LM4880, and LM4881 (SOIC)

### 2 Applications

- Smart Phones and Wireless Handsets
- Portable Tablets
- Notebook PCs and Docking Stations

### 3 Description

The TPA6111A2 is a stereo audio power amplifier packaged in either an 8-pin SOIC or an 8-pin PowerPAD MSOP package capable of delivering 150 mW of continuous RMS power per channel into 16- $\Omega$  loads. Amplifier gain is externally configured by means of two resistors per input channel and does not require external compensation for settings of 0 to 20 dB.

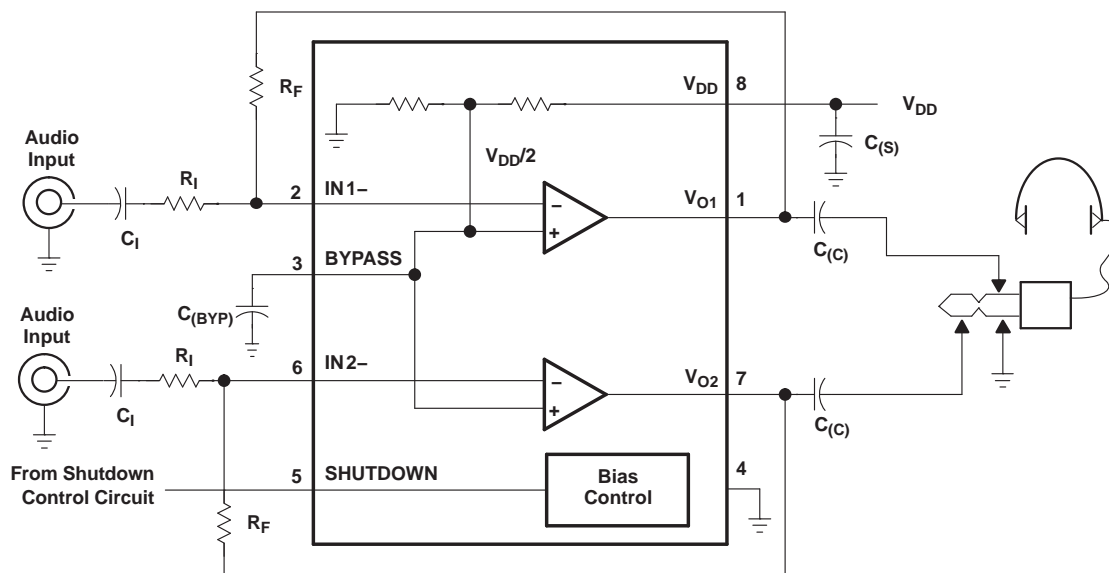
THD+N, when driving a 16- $\Omega$  load from 5 V, is 0.03% at 1 kHz, and less than 1% across the audio band of 20 Hz to 20 kHz. For 32- $\Omega$  loads, the THD+N is reduced to less than 0.02% at 1 kHz, and is less than 1% across the audio band of 20 Hz to 20 kHz. For 10-k $\Omega$  loads, the THD+N performance is 0.005% at 1 kHz, and less than 0.5% across the audio band of 20 Hz to 20 kHz.

#### Device Information<sup>(1)</sup>

| PART NUMBER | PACKAGE  | BODY SIZE (NOM)   |
|-------------|----------|-------------------|
| TPA6111A2   | SOIC (8) | 4.90 mm x 3.91 mm |
|             | MSOP (8) | 3.00 mm x 3.00 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

#### Typical Application Circuit



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

### Changes from Revision B (June 2014) to Revision C

Page

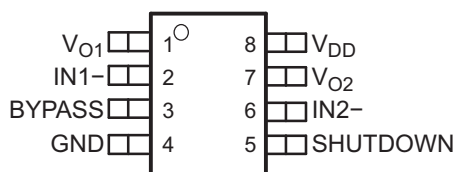
- Added *Device Comparison* table, *ESD Ratings* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section..... **1**
- Removed *Dissipation Ratings* table .....

## 5 Device Comparison Table

| AVAILABLE OPTIONS  | TPA6100A2               | TPA6110A2  | TPA6111A2              | TPA6112A2   |
|--------------------|-------------------------|------------|------------------------|-------------|
| Headphone Channels | Stereo                  | Stereo     | Stereo                 | Stereo      |
| Output Power (W)   | 0.05                    | 0.15       | 0.15                   | 0.15        |
| PSRR (dB)          | 72                      | 83         | 83                     | 83          |
| Pin/Package        | 8-pin SOIC, 8-Pin VSSOP | 8-pin MSOP | 8-pin MSOP, 8-Pin SOIC | 10-pin MSOP |

## 6 Pin Configuration and Functions

**D or DGN Package  
8-Pin SOIC or MSOP  
Top View**



**Pin Functions**

| PIN             |     | I/O | DESCRIPTION   |
|-----------------|-----|-----|---|
| NAME            | NO. |     |   |
| BYPASS          | 3   | I   | Tap to voltage divider for internal mid-supply bias supply. Connect to a 0.1- $\mu$ F to 1- $\mu$ F low ESR capacitor for best performance. |
| GND             | 4   | I   | GND is the ground connection.   |
| IN1-            | 2   | I   | IN1- is the inverting input for channel 1.  |
| IN2-            | 6   | I   | IN2- is the inverting input for channel 2.  |
| SHUTDO<br>WN    | 5   | I   | Puts the device in a low quiescent current mode when held high  |
| V <sub>DD</sub> | 8   | I   | V <sub>DD</sub> is the supply voltage terminal.   |
| V <sub>O1</sub> | 1   | O   | V <sub>O1</sub> is the audio output for channel 1.  |
| V <sub>O2</sub> | 7   | O   | V <sub>O2</sub> is the audio output for channel 2.  |

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) <sup>(1)</sup>

|                  |  | MIN                | MAX                   | UNIT |
|------------------|--|--------------------|-----------------------|------|
| V <sub>DD</sub>  | Supply voltage   |                    | 6                     | V    |
| V <sub>I</sub>   | Input voltage  | -0.3               | V <sub>DD</sub> + 0.3 | V    |
|                  | Continuous total power dissipation                           | Internally Limited |                       |      |
| T <sub>J</sub>   | Operating junction temperature                               | -40                | 150                   | °C   |
|                  | Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds |                    | 260                   | °C   |
| T <sub>stg</sub> | Storage temperature  | -65                | 150                   | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## 7.2 ESD Ratings

|             |                         | VALUE  | UNIT  |
|-------------|-------------------------|--|-------|
| $V_{(ESD)}$ | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 |
|             |                         | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±1500 |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## 7.3 Recommended Operating Conditions

|          |                                     | MIN            | MAX | UNIT |
|----------|-------------------------------------|----------------|-----|------|
| $V_{DD}$ | Supply voltage                      | 2.5            | 5.5 | V    |
| $T_A$    | Operating free-air temperature      | –40            | 85  | °C   |
| $V_{IH}$ | High-level input voltage (SHUTDOWN) | 60% × $V_{DD}$ |     | V    |
| $V_{IL}$ | Low-level input voltage (SHUTDOWN)  | 25% × $V_{DD}$ |     | V    |

## 7.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> | TPA6111A2                                    |            | UNIT |      |
|-------------------------------|--|------------|------|------|
|                               | D (SOIC)                                     | DGN (MSOP) |      |      |
|                               | 8 PINS                                       | 8 PINS     |      |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 114.7      | 55.9 | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 59.0       | 47.3 | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 54.9       | 36.4 | °C/W |
| $\psi_{JT}$                   | Junction-to-top characterization parameter   | 14.2       | 2.3  | °C/W |
| $\psi_{JB}$                   | Junction-to-board characterization parameter | 54.4       | 36.2 | °C/W |
| $R_{\theta JC(bot)}$          | Junction-to-case (bottom) thermal resistance | —          | 9.2  | °C/W |

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 7.5 DC Electrical Characteristics, $V_{DD} = 3.3\text{ V}$

at  $V_{DD} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$  (unless otherwise noted)

| PARAMETER    | TEST CONDITIONS                 | MIN                                       | TYP | MAX | UNIT |
|--------------|---------------------------------|---|-----|-----|------|
| $V_{OO}$     | Output offset voltage           |   |     | 10  | mV   |
| PSRR         | Power supply rejection ratio    | $V_{DD} = 3.2\text{ V}$ to $3.4\text{ V}$ |     | 70  | dB   |
| $I_{DD}$     | Supply current                  | SHUTDOWN (pin 5) = 0 V                    |     | 1.5 | 3    |
| $I_{DD(SD)}$ | Supply current in shutdown mode | SHUTDOWN (pin 5) = $V_{DD}$               |     | 1   | 10   |
| $Z_i$        | Input impedance                 |   | > 1 |     | MΩ   |

## 7.6 AC Operating Characteristics, $V_{DD} = 3.3\text{ V}$

$V_{DD} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $R_L = 16\ \Omega$

| PARAMETER | TEST CONDITIONS                   | MIN  | TYP | MAX  | UNIT    |
|-----------|-----------------------------------|--|-----|------|---------|
| $P_O$     | Output power (each channel)       | THD ≤ 0.1%, $f = 1\text{ kHz}$                       |     | 60   | mW      |
| THD+N     | Total harmonic distortion + noise | $P_O = 40\text{ mW}$ , 20 Hz – 20 kHz                |     | 0.4% |         |
| $B_{OM}$  | Maximum output power BW           | G = 20 dB, THD < 5%                                  |     | > 20 | kHz     |
|           | Phase margin                      | Open-loop  |     | 96°  |         |
|           | Supply ripple rejection           | $f = 1\text{ kHz}$ , $C_{(BYP)} = 0.47\ \mu\text{F}$ |     | 71   | dB      |
|           | Channel/channel output separation | $f = 1\text{ kHz}$ , $P_O = 40\text{ mW}$            |     | 89   | dB      |
| SNR       | Signal-to-noise ratio             | $P_O = 50\text{ mW}$ , $A_V = 1$                     |     | 100  | dB      |
| $V_n$     | Noise output voltage              | $A_V = 1$  |     | 11   | μV(rms) |

## 7.7 DC Electrical Characteristics, $V_{DD} = 5.5\text{ V}$

 $V_{DD} = 5.5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ 

| PARAMETER    |                                     | TEST CONDITIONS                              | MIN | TYP | MAX | UNIT          |
|--------------|-------------------------------------|--|-----|-----|-----|---------------|
| $V_{OO}$     | Output offset voltage               |  |     |     | 10  | mV            |
| PSRR         | Power supply rejection ratio        | $V_{DD} = 4.9\text{ V to } 5.1\text{ V}$     |     | 70  |     | dB            |
| $I_{DD}$     | Supply current                      | SHUTDOWN (pin 5) = 0 V                       |     | 1.6 | 3.2 | mA            |
| $I_{DD(SD)}$ | Supply current in shutdown mode     | SHUTDOWN (pin 5) = $V_{DD}$                  |     | 1   | 10  | $\mu\text{A}$ |
| $ I_{IH} $   | High-level input current (SHUTDOWN) | $V_{DD} = 5.5\text{ V}$ , $V_I = V_{DD}$     |     |     | 1   | $\mu\text{A}$ |
| $ I_{IL} $   | Low-level input current (SHUTDOWN)  | $V_{DD} = 5.5\text{ V}$ , $V_I = 0\text{ V}$ |     |     | 1   | $\mu\text{A}$ |
| $Z_i$        | Input impedance                     |  |     | > 1 |     | M $\Omega$    |

## 7.8 AC Operating Characteristics, $V_{DD} = 5.5\text{ V}$

 $V_{DD} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $R_L = 6\ \Omega$ 

| PARAMETER |                                   | TEST CONDITIONS                                      | MIN | TYP  | MAX | UNIT               |
|-----------|-----------------------------------|--|-----|------|-----|--------------------|
| $P_O$     | Output power (each channel)       | THD $\leq 0.1\%$ , $f = 1\text{ kHz}$                |     | 150  |     | mW                 |
| THD+N     | Total harmonic distortion + noise | $P_O = 100\text{ mW}$ , 20 Hz – 20 kHz               |     | 0.6% |     |                    |
| $B_{OM}$  | Maximum output power BW           | G = 20 dB, THD < 5%                                  |     | > 20 |     | kHz                |
|           | Phase margin                      | Open-loop  |     | 96°  |     |                    |
|           | Supply ripple rejection           | $f = 1\text{ kHz}$ , $C_{(BYP)} = 0.47\ \mu\text{F}$ |     | 61   |     | dB                 |
|           | Channel/channel output separation | $f = 1\text{ kHz}$ , $P_O = 100\text{ mW}$           |     | 90   |     | dB                 |
| SNR       | Signal-to-noise ratio             | $P_O = 100\text{ mW}$ , $A_V = 1$                    |     | 100  |     | dB                 |
| $V_n$     | Noise output voltage              | $A_V = 1$  |     | 11.7 |     | $\mu\text{V(rms)}$ |

## 7.9 AC Operating Characteristics, $V_{DD} = 3.3\text{ V}$

 $V_{DD} = 3.3\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $R_L = 32\ \Omega$ 

| PARAMETER |                                   | TEST CONDITIONS                                      | MIN | TYP  | MAX | UNIT               |
|-----------|-----------------------------------|--|-----|------|-----|--------------------|
| $P_O$     | Output power (each channel)       | THD $\leq 0.1\%$ , $f = 1\text{ kHz}$                |     | 35   |     | mW                 |
| THD+N     | Total harmonic distortion + noise | $P_O = 40\text{ mW}$ , 20 Hz – 20 kHz                |     | 0.4% |     |                    |
| $B_{OM}$  | Maximum output power BW           | G = 20 dB, THD < 2%                                  |     | > 20 |     | kHz                |
|           | Phase margin                      | Open-loop  |     | 96°  |     |                    |
|           | Supply ripple rejection           | $f = 1\text{ kHz}$ , $C_{(BYP)} = 0.47\ \mu\text{F}$ |     | 71   |     | dB                 |
|           | Channel/channel output separation | $f = 1\text{ kHz}$ , $P_O = 25\text{ mW}$            |     | 75   |     | dB                 |
| SNR       | Signal-to-noise ratio             | $P_O = 90\text{ mW}$ , $A_V = 1$                     |     | 100  |     | dB                 |
| $V_n$     | Noise output voltage              | $A_V = 1$  |     | 11   |     | $\mu\text{V(rms)}$ |

## 7.10 AC Operating Characteristics, $V_{DD} = 5\text{ V}$

 $V_{DD} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ ,  $R_L = 32\ \Omega$ 

| PARAMETER |                                   | TEST CONDITIONS                                      | MIN | TYP  | MAX | UNIT               |
|-----------|-----------------------------------|--|-----|------|-----|--------------------|
| $P_O$     | Output power (each channel)       | THD $\leq 0.1\%$ , $f = 1\text{ kHz}$                |     | 90   |     | mW                 |
| THD+N     | Total harmonic distortion + noise | $P_O = 20\text{ mW}$ , 20 Hz – 20 kHz                |     | 2%   |     |                    |
| $B_{OM}$  | Maximum output power BW           | G = 20 dB, THD < 2%                                  |     | > 20 |     | kHz                |
|           | Phase margin                      | Open-loop  |     | 97°  |     |                    |
|           | Supply ripple rejection           | $f = 1\text{ kHz}$ , $C_{(BYP)} = 0.47\ \mu\text{F}$ |     | 61   |     | dB                 |
|           | Channel/channel output separation | $f = 1\text{ kHz}$ , $P_O = 65\text{ mW}$            |     | 98   |     | dB                 |
| SNR       | Signal-to-noise ratio             | $P_O = 90\text{ mW}$ , $A_V = 1$                     |     | 104  |     | dB                 |
| $V_n$     | Noise output voltage              | $A_V = 1$  |     | 11.7 |     | $\mu\text{V(rms)}$ |

## 7.11 Typical Characteristics

Table 1. Table of Graphs

|          |   | FIGURE   |
|----------|---|--|
| THD+N    | Total harmonic distortion + noise vs Frequency    | Figure 1, Figure 3, Figure 5, Figure 6, Figure 7, Figure 9, Figure 11, Figure 13 |
|          | Total harmonic distortion + noise vs Output power | Figure 2, Figure 4, Figure 8, Figure 10, Figure 12, Figure 14                    |
|          | Supply ripple rejection ratio vs Frequency        | Figure 15, Figure 16   |
| $V_n$    | Output noise voltage vs Frequency                 | Figure 17, Figure 18   |
|          | Crosstalk vs Frequency                            | Figure 19-Figure 24  |
|          | Shutdown attenuation vs Frequency                 | Figure 25, Figure 26   |
|          | Open-loop gain and phase margin vs Frequency      | Figure 27, Figure 28   |
|          | Output power vs Load resistance                   | Figure 29, Figure 30   |
| $I_{DD}$ | Supply current vs Supply voltage                  | Figure 31  |
| SNR      | Signal-to-noise ratio vs Voltage gain             | Figure 32  |
|          | Power dissipation and amplifier vs Load power     | Figure 33, Figure 34   |

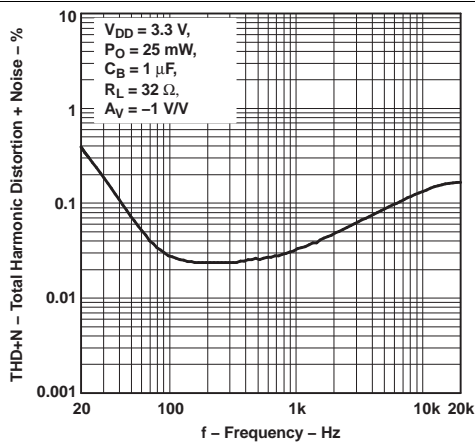


Figure 1. Total Harmonic Distortion + Noise vs Frequency

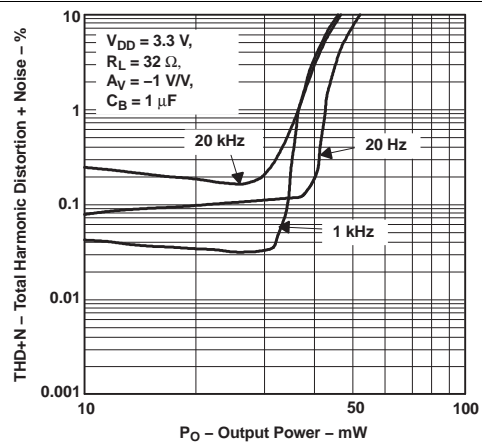


Figure 2. Total Harmonic Distortion + Noise vs Output Power

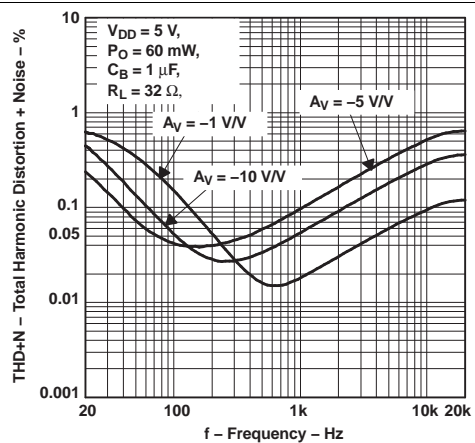


Figure 3. Total Harmonic Distortion + Noise vs Frequency

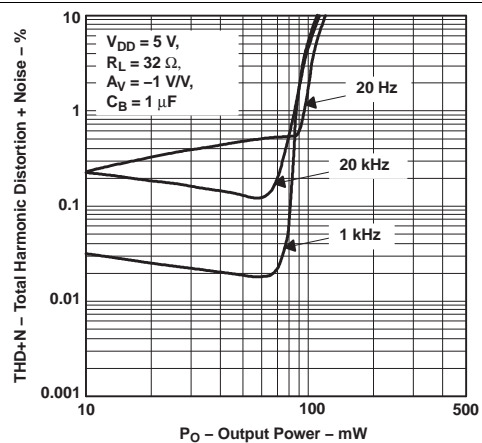


Figure 4. Total Harmonic Distortion + Noise vs Output Power

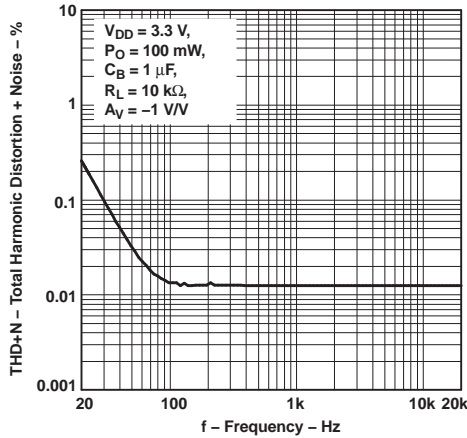


Figure 5. Total Harmonic Distortion + Noise vs Frequency

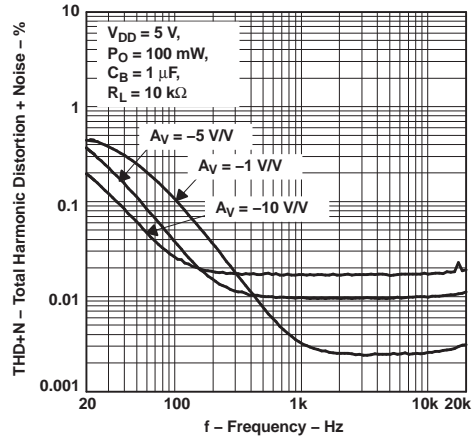


Figure 6. Total Harmonic Distortion + Noise vs Frequency

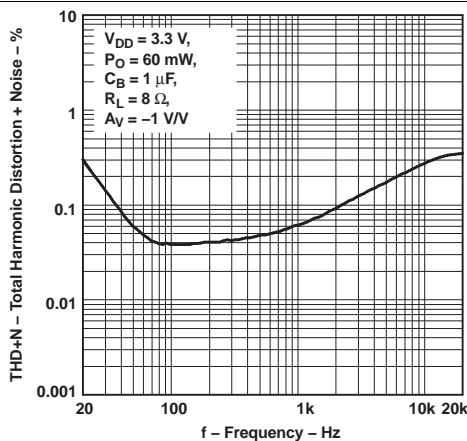


Figure 7. Total Harmonic Distortion + Noise vs Frequency

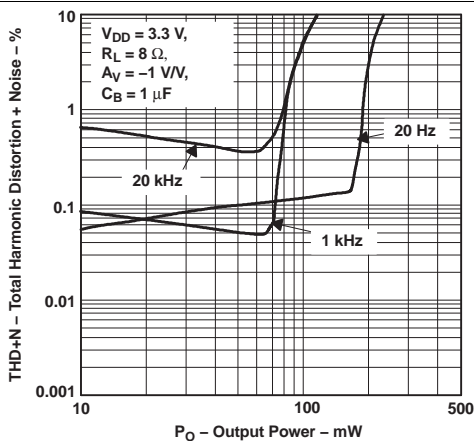


Figure 8. Total Harmonic Distortion + Noise vs Output Power

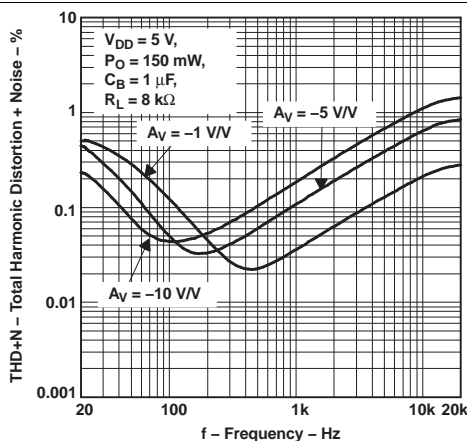


Figure 9. Total Harmonic Distortion + Noise vs Frequency

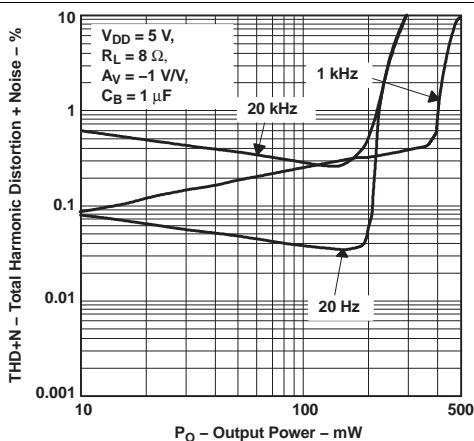


Figure 10. Total Harmonic Distortion + Noise vs Output Power

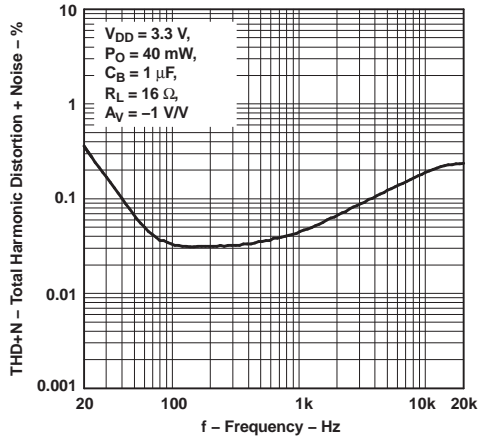


Figure 11. Total Harmonic Distortion + Noise vs Frequency

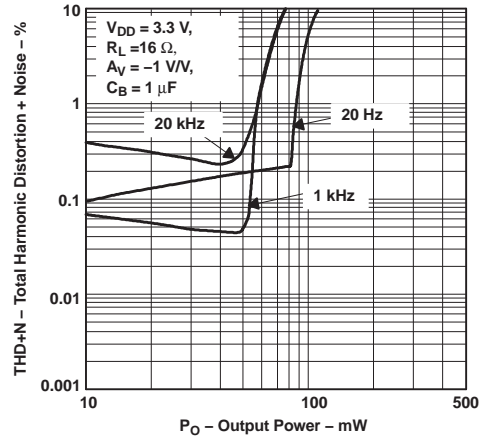


Figure 12. Total Harmonic Distortion + Noise vs Output Power

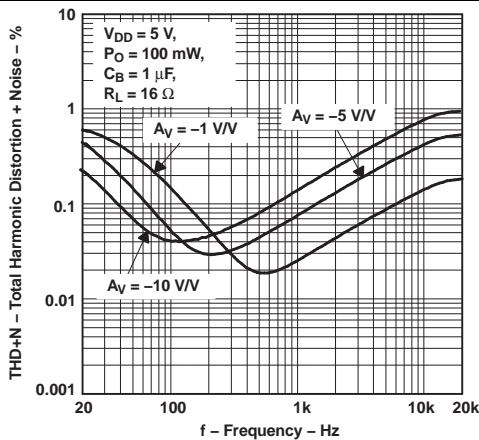


Figure 13. Total Harmonic Distortion + Noise vs Frequency

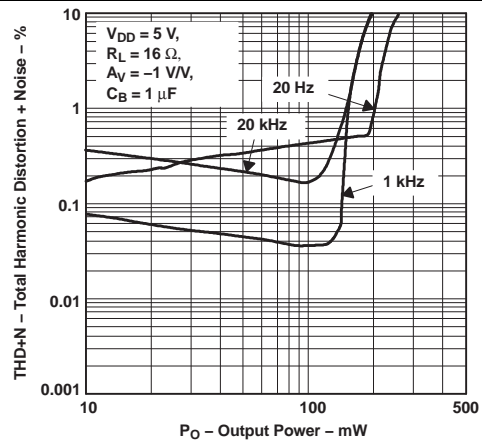


Figure 14. Total Harmonic Distortion + Noise vs Output Power

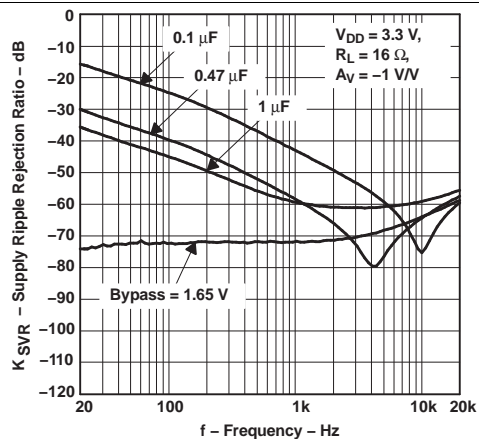


Figure 15. Supply Ripple Rejection Ratio vs Frequency

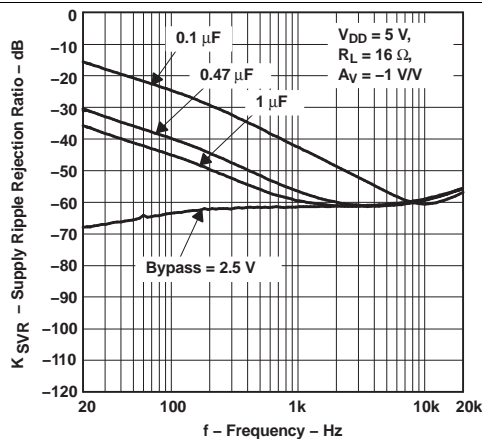


Figure 16. Supply Ripple Rejection Ratio vs Frequency



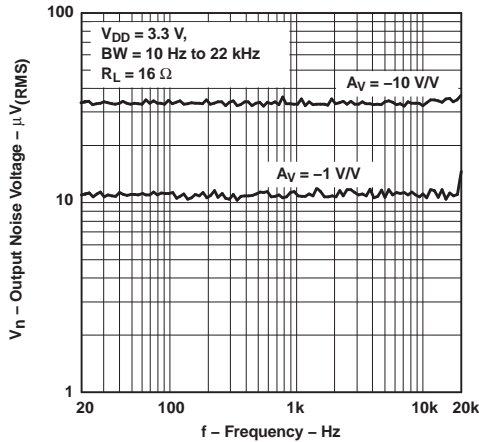


Figure 17. Output Noise Voltage vs Frequency

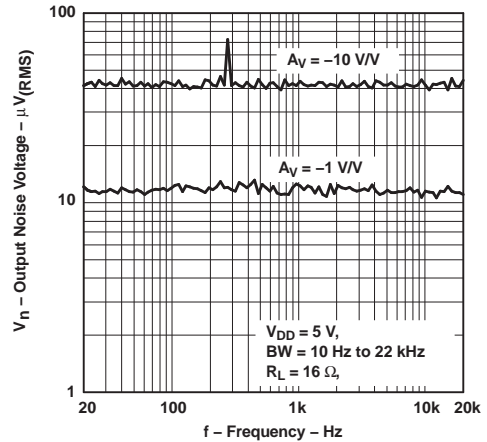


Figure 18. Output Noise Voltage vs Frequency

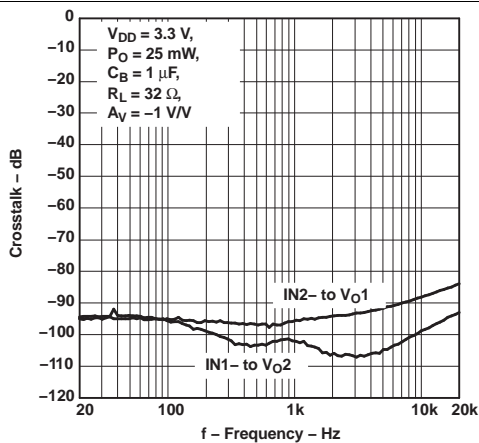


Figure 19. Crosstalk vs Frequency

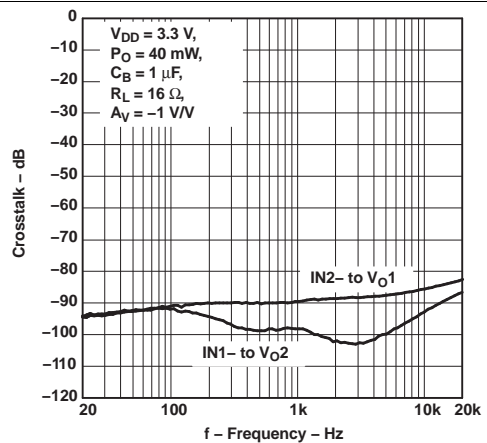


Figure 20. Crosstalk vs Frequency

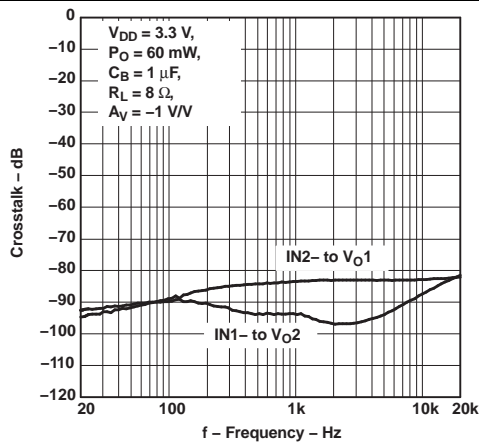


Figure 21. Crosstalk vs Frequency

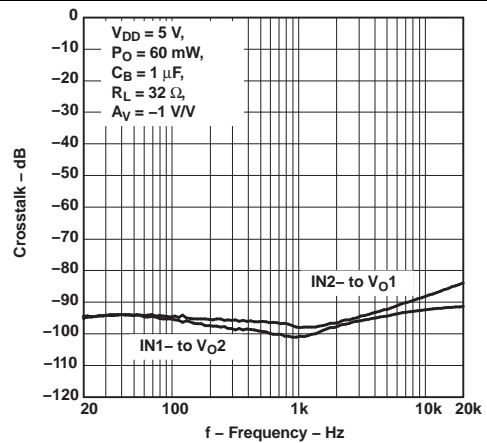
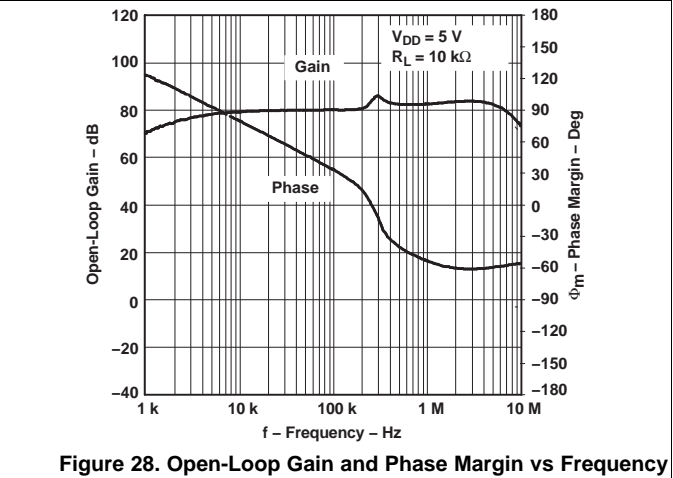
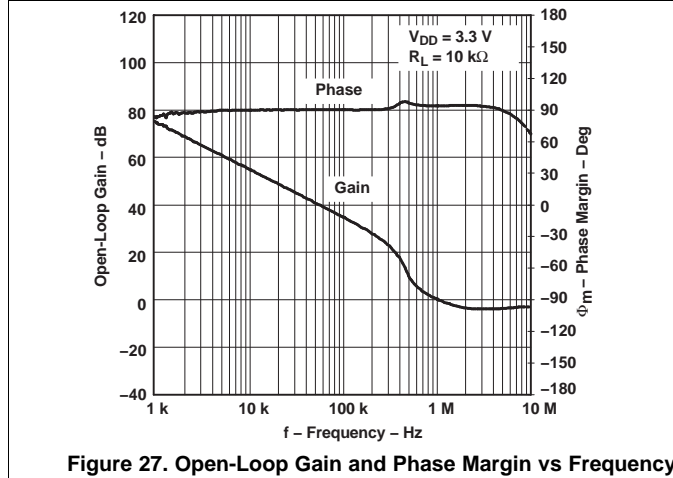
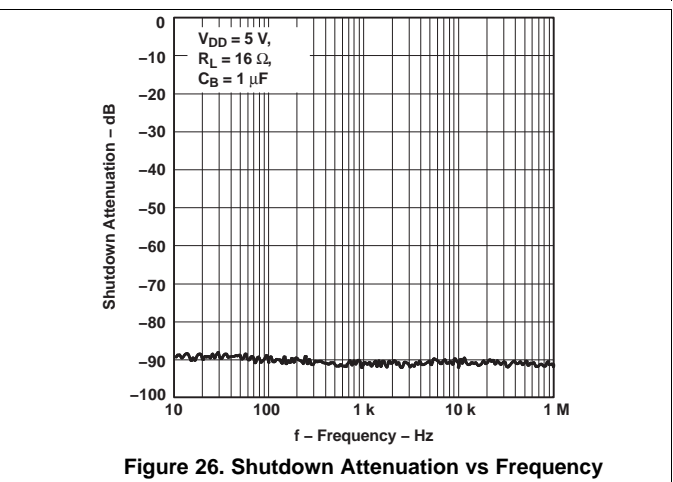
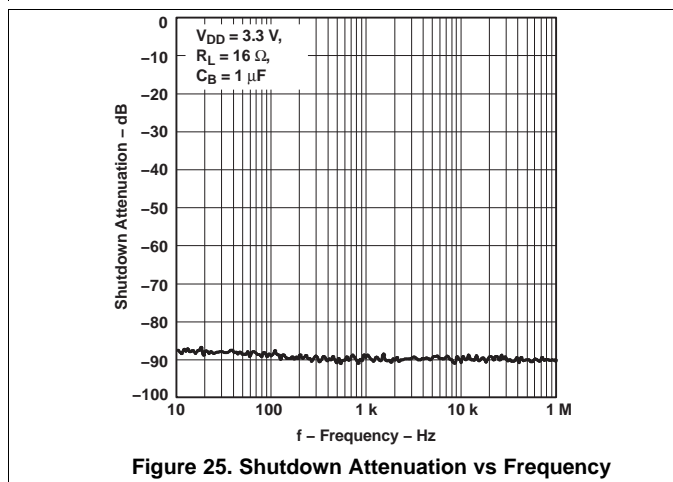
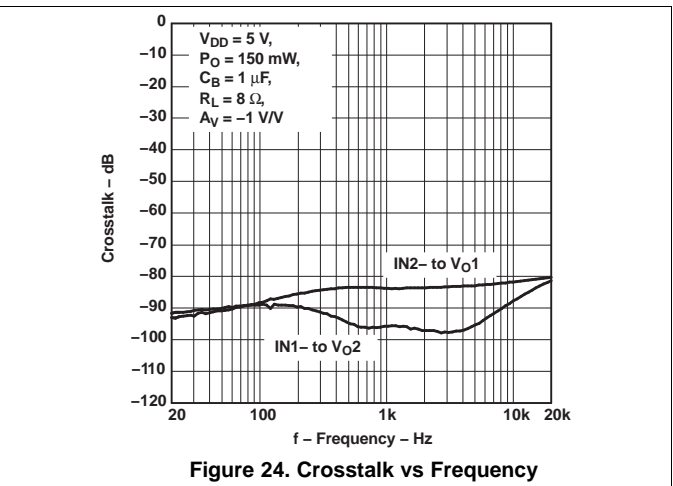
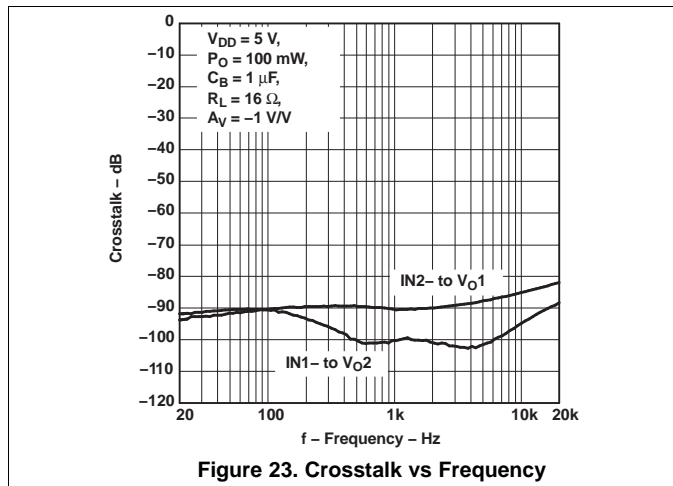


Figure 22. Crosstalk vs Frequency



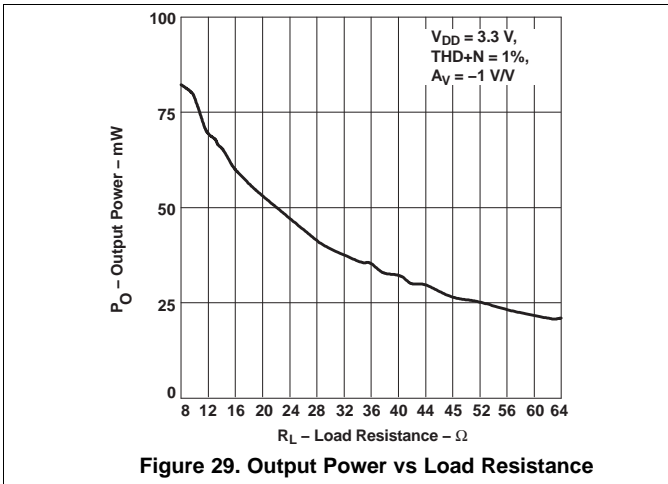


Figure 29. Output Power vs Load Resistance

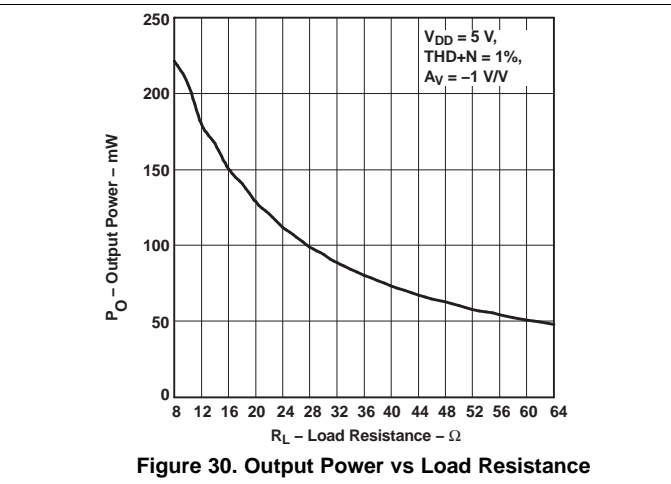


Figure 30. Output Power vs Load Resistance

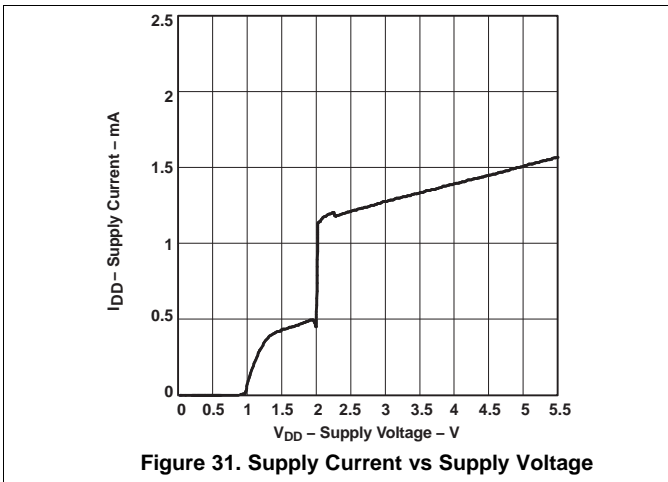


Figure 31. Supply Current vs Supply Voltage

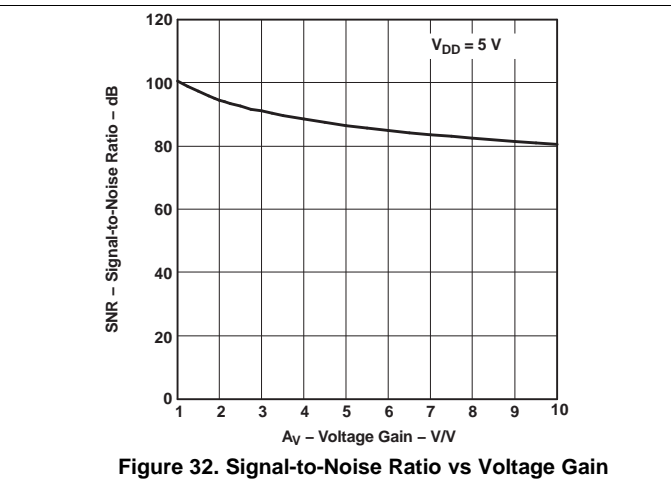


Figure 32. Signal-to-Noise Ratio vs Voltage Gain

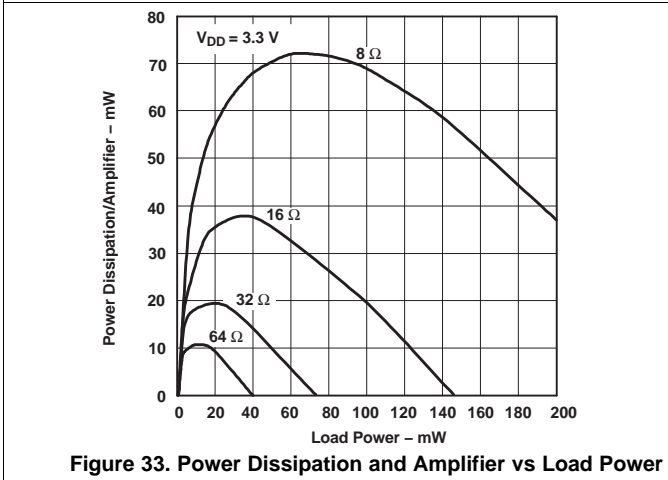


Figure 33. Power Dissipation and Amplifier vs Load Power

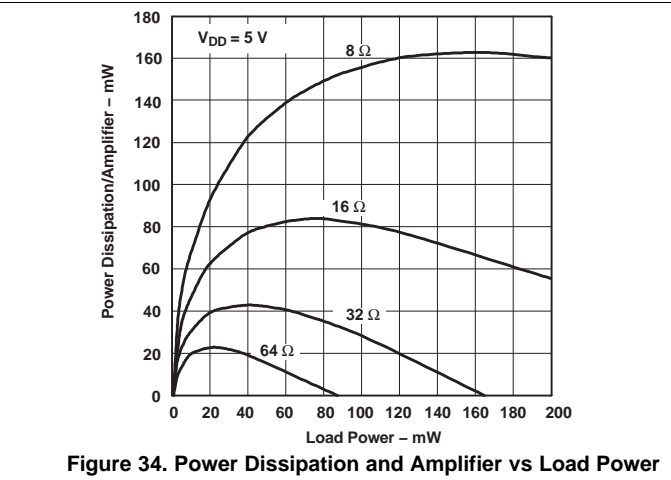


Figure 34. Power Dissipation and Amplifier vs Load Power

## 8 Parameter Measurement Information

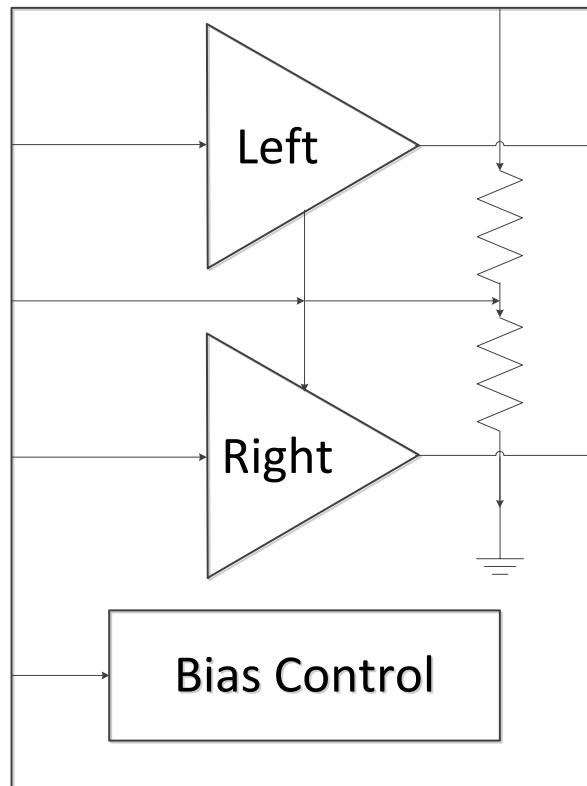
All parameters are measured according to the conditions described in the [Specifications](#) section.

## 9 Detailed Description

### 9.1 Overview

The TPA6111A2 device is a stereo audio power amplifier available in 8-pin SOIC and 8-pin MSOP packages. This device is able to deliver 150 mW of continuous RMS power per channel into 16-Ω loads. The gain of the amplifier is externally configured from 0 dB to 20 dB through two resistors per channel. The TPA6111A2 device is fully specified for operation at 3.3 V and 5 V, which makes this device ideal for PC and mobile applications.

### 9.2 Functional Block Diagram



### 9.3 Feature Description

#### 9.3.1 5-V Versus 3.3-V Operation

The TPA6111A2 was designed for operation over a supply range of 2.5 V to 5.5 V. This data sheet provides full specifications for 5-V and 3.3-V operation because these are considered to be the two most common standard voltages. There are no special considerations for 3.3-V versus 5-V operation as far as supply bypassing, gain setting, or stability. The most important consideration is that of output power. Each amplifier in the TPA6111A2 can produce a maximum voltage swing of  $V_{DD} - 1$  V. This means, for 3.3-V operation, clipping starts to occur when  $V_{O(PP)} = 2.3$  V as opposed when  $V_{O(PP)} = 4$  V while operating at 5 V. The reduced voltage swing subsequently reduces maximum output power into the load before distortion begins to become significant.

### 9.4 Device Functional Modes

The TPA6111A2 can be put in shutdown mode when asserting SHUTDOWN pin to a logic HIGH level. While in shutdown mode, the device is turned off, making the current consumption very low. The device exits shutdown mode when a LOW logic level is applied to SHUTDOWN pin.

## 10 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 10.1 Application Information

This typical connection diagram highlights the required external components and system level connections for proper operation of the device in popular use case. Any design variation can be supported by TI through schematic and layout reviews. Visit <http://e2e.ti.com> for design assistance and join the audio amplifier discussion forum for additional information.

### 10.2 Typical Application

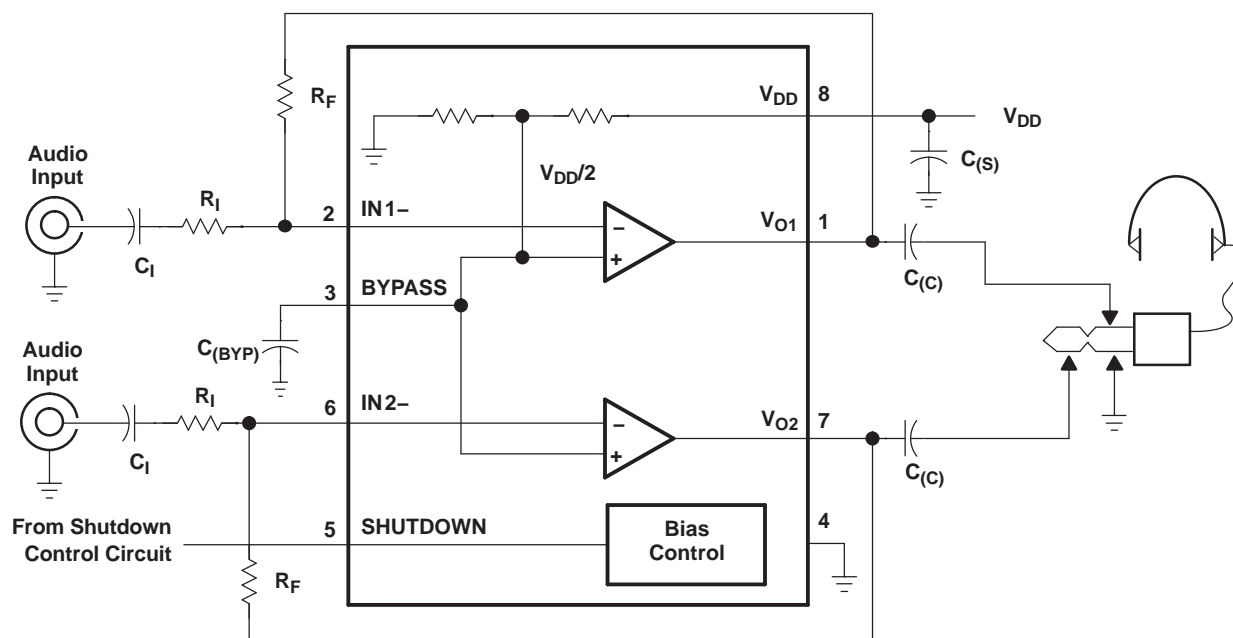


Figure 35. Typical Application

#### 10.2.1 Design Requirements

Table 2 lists the design requirements of the TPA111A2.

Table 2. Design Requirements

| DESIGN PARAMETER           | EXAMPLE VALUE |
|----------------------------|---------------|
| Input voltage supply range | 3.3 V to 5 V  |
| Current                    | 2 mA          |
| Load impedance             | 16 $\Omega$   |

## 10.2.2 Detailed Design Procedure

### 10.2.2.1 Gain Setting Resistors, $R_F$ and $R_I$

The gain for the TPA6111A2 is set by resistors  $R_F$  and  $R_I$  according to [Equation 1](#).

$$\text{Gain} = -\left(\frac{R_F}{R_I}\right) \quad (1)$$

Given that the TPA6111A2 is a MOS amplifier, the input impedance is high. Consequently, input leakage currents are not generally a concern, although noise in the circuit increases as the value of  $R_F$  increases. In addition, a certain range of  $R_F$  values is required for proper start-up operation of the amplifier. Taken together, TI recommends that the effective impedance seen by the inverting node of the amplifier be set between 5 k $\Omega$  and 20 k $\Omega$ . The effective impedance is calculated in [Equation 2](#).

$$\text{Effective Impedance} = -\left(\frac{R_F R_I}{R_F + R_I}\right) \quad (2)$$

As an example, consider an input resistance of 20 k $\Omega$  and a feedback resistor of 20 k $\Omega$ . The gain of the amplifier would be  $-1$  and the effective impedance at the inverting terminal would be 10 k $\Omega$ , which is within the recommended range.

For high-performance applications, metal film resistors are recommended because they tend to have lower noise levels than carbon resistors. For values of  $R_F$  above 50 k $\Omega$ , the amplifier tends to become unstable due to a pole formed from  $R_F$  and the inherent input capacitance of the MOS input structure. For this reason, a small compensation capacitor of approximately 5 pF must be placed in parallel with  $R_F$ . In effect, this creates a low-pass filter network with the cutoff frequency defined in [Equation 3](#).

$$f_{c(\text{lowpass})} = \frac{1}{2\pi R_F C_F} \quad (3)$$

For example, if  $R_F$  is 100 k $\Omega$  and  $C_F$  is 5 pF, then  $f_{c(\text{lowpass})}$  is 318 kHz, which is well outside the audio range.

### 10.2.2.2 Input Capacitor, $C_I$

In the typical application, input capacitor  $C_I$  is required to allow the amplifier to bias the input signal to the proper DC level for optimum operation. In this case,  $C_I$  and  $R_I$  form a high-pass filter with the corner frequency determined in [Equation 4](#).

$$f_{c(\text{highpass})} = \frac{1}{2\pi R_I C_I} \quad (4)$$

The value of  $C_I$  is important to consider, as it directly affects the bass (low-frequency) performance of the circuit. Consider the example where  $R_I$  is 20 k $\Omega$  and the specification calls for a flat bass response down to 20 Hz. [Equation 4](#) is reconfigured as [Equation 5](#).

$$C_I = \frac{1}{2\pi R_I f_{c(\text{highpass})}} \quad (5)$$

In this example,  $C_I$  is 0.40  $\mu\text{F}$ , so TI recommends choosing a value in the range of 0.47  $\mu\text{F}$  to 1  $\mu\text{F}$ . A further consideration for this capacitor is the leakage path from the input source through the input network ( $R_I$ ,  $C_I$ ) and the feedback resistor ( $R_F$ ) to the load. This leakage current creates a DC offset voltage at the input to the amplifier that reduces useful headroom, especially in high-gain applications ( $> 10$ ). For this reason a low-leakage tantalum or ceramic capacitor is the best choice. When polarized capacitors are used, the positive side of the capacitor must face the amplifier input in most applications, as the DC level there is held at  $V_{DD}/2$ , which is likely higher than the source DC level.

---

#### NOTE

It is important to confirm the capacitor polarity in the application.

---

### 10.2.2.3 Power Supply Decoupling, $C_{(S)}$

The TPA6111A2 is a high-performance CMOS audio amplifier that requires adequate power supply decoupling to ensure that the output total harmonic distortion (THD) is as low as possible. Power supply decoupling also prevents oscillations for long lead lengths between the amplifier and the speaker. The optimum decoupling is achieved by using two capacitors of different types that target different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 0.1  $\mu\text{F}$ , placed as close as possible to the device  $V_{\text{DD}}$  lead, works best. For filtering lower frequency noise signals, a larger aluminum electrolytic capacitor of 10  $\mu\text{F}$  or greater placed near the power amplifier is recommended.

### 10.2.2.4 Midrail Bypass Capacitor, $C_{(BYP)}$

The midrail bypass capacitor,  $C_{(BYP)}$ , serves several important functions. During start-up,  $C_{(BYP)}$  determines the rate at which the amplifier starts up. This helps to push the start-up pop noise into the subaudible range (so low it cannot be heard). The second function is to reduce noise produced by the power supply caused by coupling into the output drive signal. This noise is from the midrail generation circuit internal to the amplifier. The capacitor is fed from a 230-k $\Omega$  source inside the amplifier. To keep the start-up pop as low as possible, the relationship shown in Equation 6 must be maintained.

$$\frac{1}{(C_{(BYP)} \times 230 \text{ k}\Omega)} \leq \frac{1}{(C_I R_I)} \quad (6)$$

As an example, consider a circuit where  $C_{(BYP)}$  is 1  $\mu\text{F}$ ,  $C_I$  is 1  $\mu\text{F}$ , and  $R_I$  is 20 k $\Omega$ . Inserting these values into Equation 6 results in:  $6.25 \leq 50$  which satisfies the rule. Recommended values for bypass capacitor  $C_{(BYP)}$  are 0.1- $\mu\text{F}$  to 1- $\mu\text{F}$ , ceramic or tantalum low-ESR, for the best THD and noise performance.

### 10.2.2.5 Output Coupling Capacitor, $C_{(C)}$

In the typical single-supply single-ended (SE) configuration, an output coupling capacitor ( $C_{(C)}$ ) is required to block the DC bias at the output of the amplifier, thus preventing DC currents in the load. As with the input coupling capacitor, the output coupling capacitor and impedance of the load form a high-pass filter governed by Equation 7.

$$f_c = \frac{1}{2\pi R_L C_{(C)}} \quad (7)$$

The main disadvantage, from a performance standpoint, is that the typically small load impedances drive the low-frequency corner higher. Large values of  $C_{(C)}$  are required to pass low frequencies into the load. Consider the example where a  $C_{(C)}$  of 68  $\mu\text{F}$  is chosen and loads vary from 32  $\Omega$  to 47 k $\Omega$ . Table 3 summarizes the frequency response characteristics of each configuration.

**Table 3. Common Load Impedances vs Low Frequency Output Characteristics in SE Mode**

| $R_L$           | $C_C$            | LOWEST FREQUENCY |
|-----------------|------------------|------------------|
| 32 $\Omega$     | 68 $\mu\text{F}$ | 73 Hz            |
| 10,000 $\Omega$ | 68 $\mu\text{F}$ | 0.23 Hz          |
| 47,000 $\Omega$ | 68 $\mu\text{F}$ | 0.05 Hz          |

As Table 3 indicates, headphone response is adequate and drive into line level inputs (a home stereo for example) is good.

The output coupling capacitor required in single-supply SE mode also places additional constraints on the selection of other components in the amplifier circuit. With the rules described earlier still valid, add the following relationship in Equation 8:

$$\frac{1}{(C_{(BYP)} \times 230 \text{ k}\Omega)} \leq \frac{1}{(C_I R_I)} \leq \frac{1}{R_L C_{(C)}} \quad (8)$$

### 10.2.2.6 Using Low-ESR Capacitors

Low-ESR capacitors are recommended throughout this application. A real capacitor can be modeled simply as a resistor in series with an ideal capacitor. The voltage drop across this resistor minimizes the beneficial effects of the capacitor in the circuit. The lower the equivalent value of this resistance, the more the real capacitor behaves like an ideal capacitor.

### 10.2.3 Application Curves

The characteristics of this design are shown in [Table 4](#) from the *Typical Characteristics* section.

**Table 4. Table of Graphs**

|  |                 | FIGURE                    |
|--|-----------------|---------------------------|
| THD+N Total harmonic distortion plus noise | vs Frequency    | <a href="#">Figure 11</a> |
|  | vs Output power | <a href="#">Figure 12</a> |

## 11 Power Supply Recommendations

The device is designed to operate from an input voltage supply of 3.3 V and 5 V. Therefore, the output voltage range of power supply must be within this range and well regulated. Ti recommends placing decoupling capacitors in every voltage source pin. Place these decoupling capacitors as close as possible to the TPA6111A2.



## 12 Layout

### 12.1 Layout Guidelines

Solder the exposed metal pad on the TPA6111A2 DGN package to the PCB. The pad on the PCB may be grounded or may be allowed to float (not be connected to ground or power). If the pad is grounded, it must be connected to the same ground as the GND pin (4). See the layout and mechanical drawings in [Mechanical, Packaging, and Orderable Information](#) for proper sizing. Soldering the thermal pad improves mechanical reliability, improves grounding of the device, and enhances thermal conductivity of the package.

### 12.2 Layout Examples

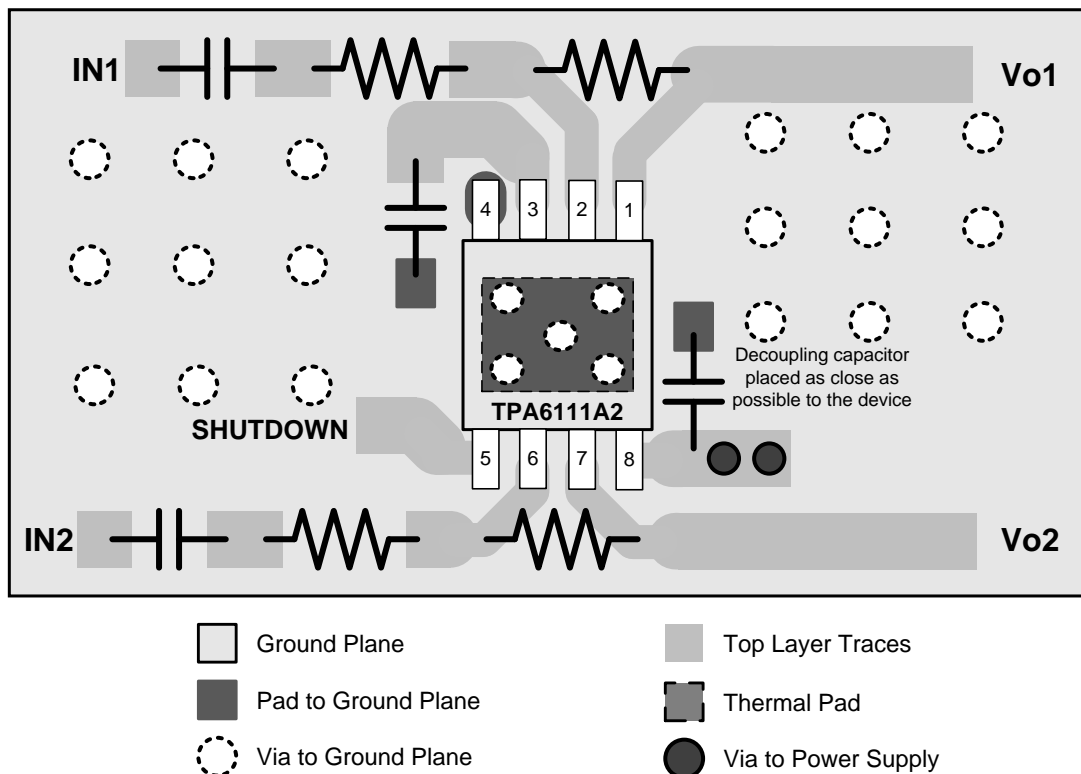
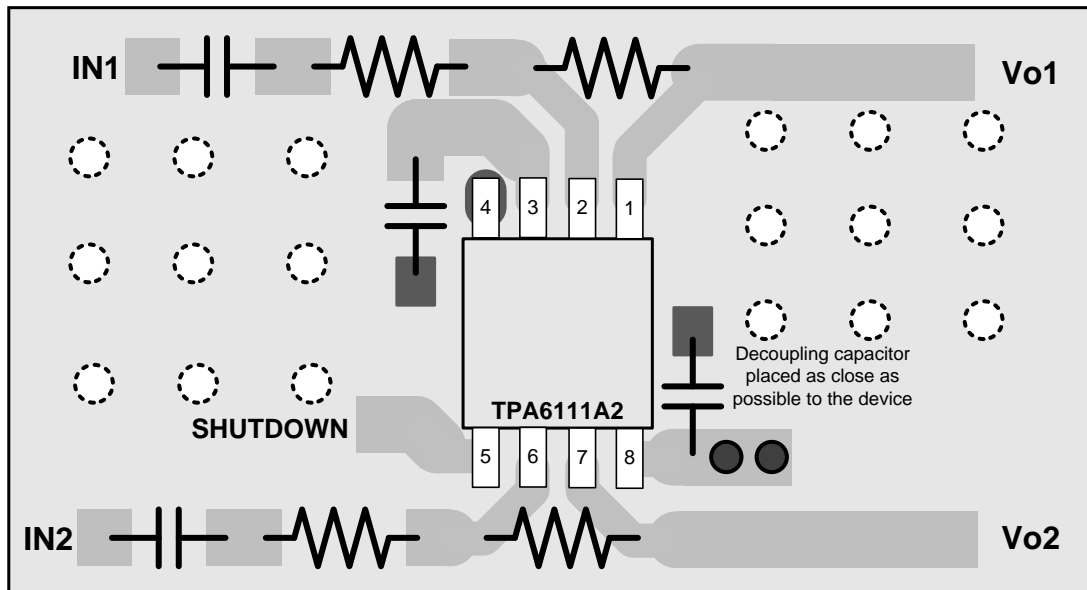


Figure 36. TPA6111A2 MSOP Layout Example

**Layout Examples (continued)**



- |  |  |
|--|--|
|  Ground Plane         |  Top Layer Traces     |
|  Pad to Ground Plane  |  Thermal Pad          |
|  Via to Ground Plane |  Via to Power Supply |

**Figure 37. TPA611A2 SOIC Layout Example**

## 13 Device and Documentation Support

### 13.1 Documentation Support

#### 13.1.1 Related Documentation

For related documentation, see the following:

*PowerPAD Thermally Enhanced Package Application Report* ([SLMA002](#))

### 13.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](#), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 13.3 Trademarks

PowerPAD, E2E are trademarks of Texas Instruments.  
All other trademarks are the property of their respective owners.

### 13.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 13.5 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| TPA6111A2D       | ACTIVE        | SOIC         | D               | 8    | 75          | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 85    | 6111A2                  | <a href="#">Samples</a> |
| TPA6111A2DGN     | ACTIVE        | HVSSOP       | DGN             | 8    | 80          | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 85    | AJA                     | <a href="#">Samples</a> |
| TPA6111A2DGNR    | ACTIVE        | HVSSOP       | DGN             | 8    | 2500        | RoHS & Green    | NIPDAU   NIPDAUAG                    | Level-1-260C-UNLIM   | -40 to 85    | AJA                     | <a href="#">Samples</a> |
| TPA6111A2DGNRG4  | ACTIVE        | HVSSOP       | DGN             | 8    | 2500        | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 85    | AJA                     | <a href="#">Samples</a> |
| TPA6111A2DR      | ACTIVE        | SOIC         | D               | 8    | 2500        | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 85    | 6111A2                  | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSELETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPA6111A2DGNR | HVSSOP       | DGN             | 8    | 2500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| TPA6111A2DGNR | HVSSOP       | DGN             | 8    | 2500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| TPA6111A2DR   | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPA6111A2DGNR | HVSSOP       | DGN             | 8    | 2500 | 364.0       | 364.0      | 27.0        |
| TPA6111A2DGNR | HVSSOP       | DGN             | 8    | 2500 | 358.0       | 335.0      | 35.0        |
| TPA6111A2DR   | SOIC         | D               | 8    | 2500 | 340.5       | 338.1      | 20.6        |

**TUBE**


\*All dimensions are nominal

| Device       | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|--------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| TPA6111A2D   | D            | SOIC         | 8    | 75  | 507    | 8      | 3940   | 4.32   |
| TPA6111A2DGN | DGN          | HVSSOP       | 8    | 80  | 330    | 6.55   | 500    | 2.88   |



## GENERIC PACKAGE VIEW

**DGN 8**

**PowerPAD VSSOP - 1.1 mm max height**

3 x 3, 0.65 mm pitch

SMALL OUTLINE PACKAGE

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4225482/A

DGN0008D



# PACKAGE OUTLINE

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4225481/A 11/2019

PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

# EXAMPLE BOARD LAYOUT

DGN0008D

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 15X



4225481/A 11/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

# EXAMPLE STENCIL DESIGN

DGN0008D

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



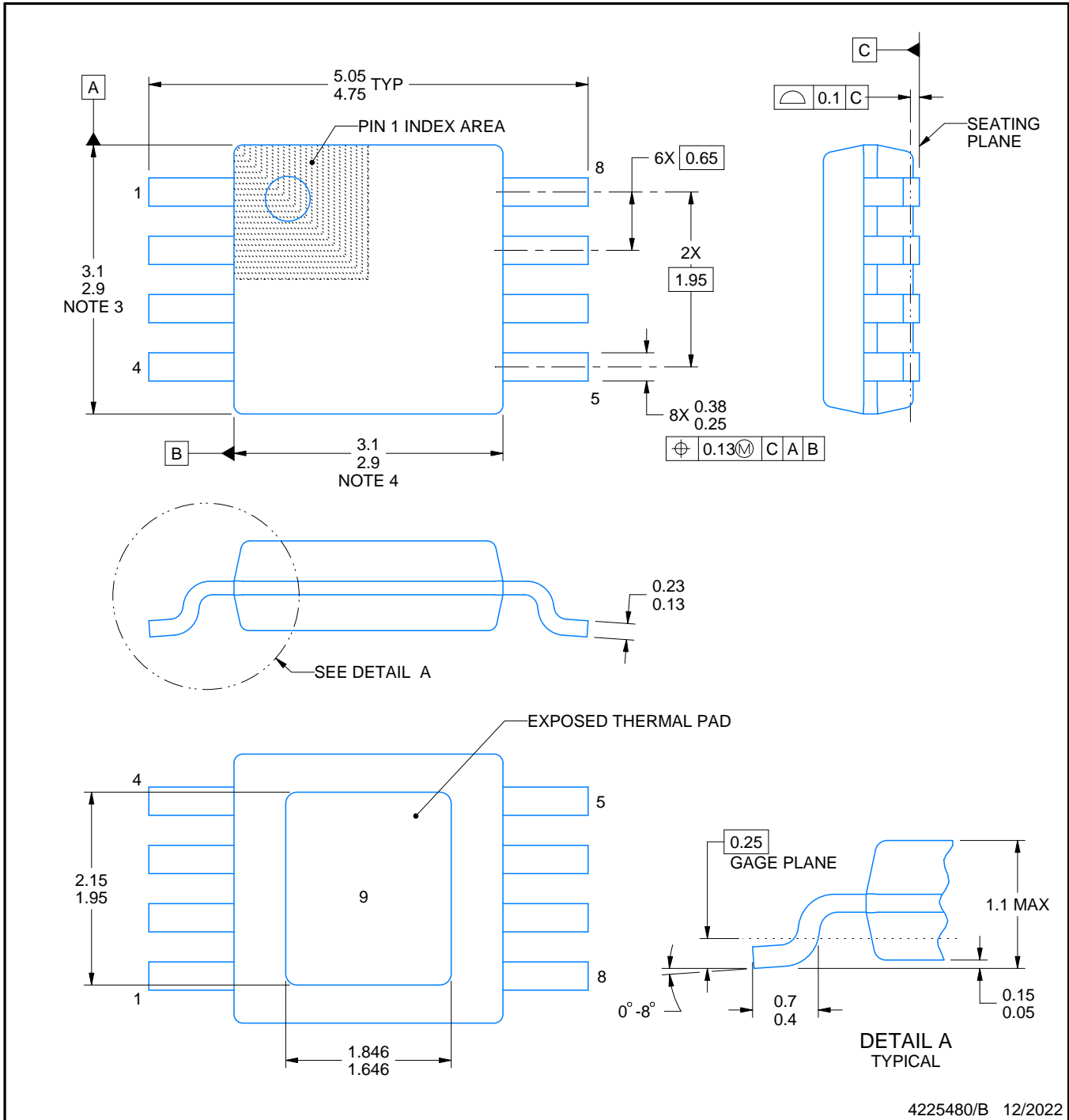
**SOLDER PASTE EXAMPLE**  
EXPOSED PAD 9:  
100% PRINTED SOLDER COVERAGE BY AREA  
SCALE: 15X

| STENCIL THICKNESS | SOLDER STENCIL OPENING |
|-------------------|------------------------|
| 0.1               | 1.76 X 2.11            |
| 0.125             | 1.57 X 1.89 (SHOWN)    |
| 0.15              | 1.43 X 1.73            |
| 0.175             | 1.33 X 1.60            |

4225481/A 11/2019

NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.



4225480/B 12/2022

PowerPAD is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

# EXAMPLE BOARD LAYOUT

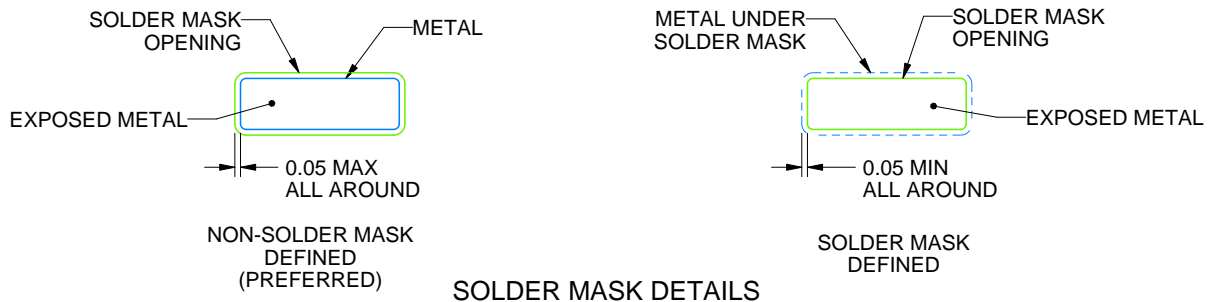
DGN0008G

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 15X



SOLDER MASK DETAILS

4225480/B 12/2022

NOTES: (continued)

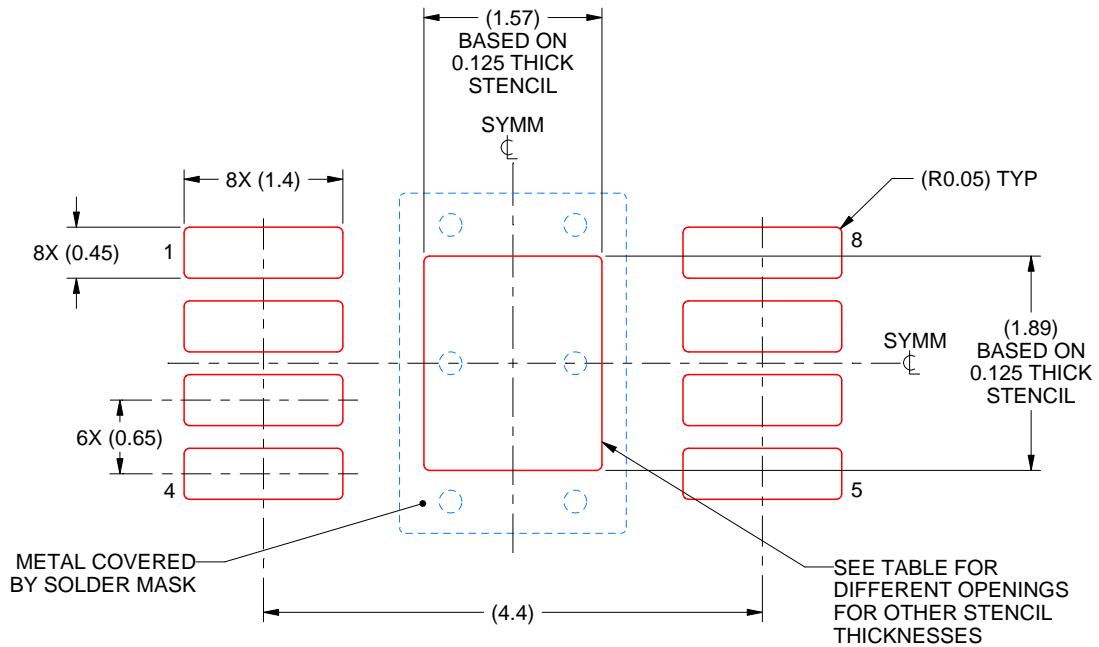
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

# EXAMPLE STENCIL DESIGN

DGN0008G

PowerPAD™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



**SOLDER PASTE EXAMPLE**  
EXPOSED PAD 9:  
100% PRINTED SOLDER COVERAGE BY AREA  
SCALE: 15X

| STENCIL THICKNESS | SOLDER STENCIL OPENING |
|-------------------|------------------------|
| 0.1               | 1.76 X 2.11            |
| 0.125             | 1.57 X 1.89 (SHOWN)    |
| 0.15              | 1.43 X 1.73            |
| 0.175             | 1.33 X 1.60            |

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NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.



D0008A

# PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed  $.006$  [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



# EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
 EXPOSED METAL SHOWN  
 SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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